

## **FEATURES**

- Large active area
- Photoconductive
- Low cost
- High speed

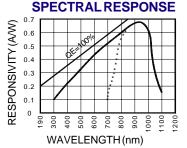
**DESCRIPTION:** The **PDB-C134** detector is a 1.55 mm<sup>2</sup> planar PIN photodiode packaged in a T 1 water clear plastic housing. Designed for high speed, low capacitance, photoconductive applications. The **PDB-C134F** includes a daylight filter.

## **APPLICATIONS**

- Smoke detectors
- Light pen detectors
- TV & VCR remotes
- Bar code detectors

## **ABSOLUTE MAXIMUM RATING** (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V <sub>BR</sub>	Reverse Voltage		100	V
T <sub>stg</sub>	Storage Temperature	-40	+100	°C
T <sub>o</sub>	Operating Temperature Range	-40	+80	°C
T <sub>s</sub>	Soldering Temperature*		+260	°C
I	Light Current		0.5	mA



\*1/16 inch from case for 3 secs max

## ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
I <sub>sc</sub>	Short Circuit Current	H = 100 fc, 2850 K	50	60		$\mu$ A
I <sub>D</sub>	Dark Current	H = 0, V <sub>R</sub> = 10 V		2	30	nA
R <sub>sh</sub>	Shunt Resistance	H = 0, V <sub>R</sub> = 10 mV	.5	2		GΩ
TCR <sub>SH</sub>	RSH Temp. Coefficient	H = 0, V <sub>R</sub> = 10 mV		-8		%/°C
C	Junction Capacitance	H = 0, V <sub>R</sub> = 10 V*		6	10	pF
λrange	Spectral Application Range	(without daylight filter)**	400		1100	nm
λρ	Spectral Response - Peak			950		nm
V <sub>BR</sub>	Breakdown Voltage	I = 10 μA	50	100		V
NEP	Noise Equivalent Power	V <sub>R</sub> = 10 V @ Peak		1.8x10 <sup>-13</sup>		W/ √ Hz
tr	Response Time	$RL = 1 K\Omega V_R = 50 V$		10		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. \* f = 1 MHz, \*\* daylight filter = 700 - 1100 nm [FORM NO. 100-PDB-C134 REV B]